









	<h2>RDD022N50TL</h2>
	<p>Hersteller-Teilenummer: RDD022N50TL</p> <p>Hersteller / Marke: LAPIS Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 500V CPT</p> <p>Datenblätter:  RDD022N50TL.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7251 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	RDD022N50TL
Hersteller	LAPIS Semiconductor
Beschreibung	MOSFET N-CH 500V CPT
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	7251 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	CPT3
Verlustleistung (max)	20W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2A (Tc)
Rds On (Max) @ Id, Vgs	5.4 Ohm @ 1A, 10V
VGS (th) (Max) @ Id	4.7V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	6.7nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	168pF @ 25V
Verpackung	Tape & Reel (TR)



















































RDD022N50TL ist neu im Original, Suche RDD022N50TL Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RDD022N50TL LAPIS Semiconductor mit Garantie und Vertrauen. Anfrage RDD022N50TL: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RDD020N60TL LAPIS Semiconductor MOSFET N-CH 600V 2A CPT3</p>	 <p>RDD022N60 TL ROHM RDD022N60 TL ROHM</p>	 <p>RDD020N60 VB RDD020N60 TL ROHM</p>	 <p>RDD022N60TL LAPIS Semiconductor MOSFET N-CH 600V CPT</p>
 <p>RDD023N50TL LAPIS Semiconductor MOSFET N-CH 500V 2A CPT3</p>	 <p>RDD020N60 TL ROHM ROHM SOT2522.5</p>	 <p>RDD020N50 TL ROHM RDD020N50 TL ROHM</p>	 <p>RDD023N50 VB RDD023N50 VB</p>

heiße Teile

Mehr

 1SMB5942BT3G	 AP1270MP	 AP130-30WL-7	 AP1301-SPLA	 AP6213A-33
 AT45DB041B-RU	 BAT64-05WH6327	 BSC017N04NS3G	 BUK9832-55	 C1005X7R1H471M050BA
 C1005X7R1V473K050BB	 CL31A106MAHNNNE	 DS1832/TR	 DSC1030BI1-080.0000T	 FAN3182AMX
 FDP023N08B	 FF150R12MT4	 FM25L16B-DG	 GRM1886P1H7R2DZ01D	 IDH06SG60C
 IL-AG5-5S-S3C1	 IRFR3504Z	 ISL24007IRZ	 IWS2405.2	 IXTH6N50D2
 K4E6E304EE-EGCE	 KSB564AYBU	 LT1641CS8#TR	 LTM2987IY#PBF	 MMGU40S120B6C
 MT5389FINU	 NCP2990FCT2G	 NE5332DR	 P4KE350A	 RDD020N50
 RDD020N60	 RDD022N60	 RDD023N50	 RDD023N50TL	 RDD050N20
 RDD050N20TL	 SF-0603S250-2	 SI4884DY	 SKM50GB174D	 SKT290F04DS
 SS5P5-M3/87A	 STF20N95K5	 T130N600	 TPS79601KTTR	 ZK2500A4000V

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